Raman scattering study of the upper phase transition in CsScF₄

A. N. Vtyurin,¹ A. Bulou,²* A. S. Krylov,¹ I. V. Shmygol¹ and K. S. Aleksandrov¹

¹ Kirensky Institute of Physics, Krasnovarsk 660036, Russia

² Laboratoire Physique de l'Etat Condensé, UPRES A CNRS No. 6087, Université du Maine, 72085 Le Mans Cédex g, France

Effects of the phase transition between the high-temperature tetragonal phases of the $CsScF_4$ crystal were studied by Raman scattering. The appearance of new lines including a soft mode was observed below the phase transition point, in complete accordance with the new crystal symmetry. The behavior of the soft mode, which corresponds to in-phase rotations of ScF_6 rigid groups around the z-axis (and out-of-phase within perovskite-like layers), resembles that observed earlier in RbAlF₄, which suggests a similar mechanism of this transition in both crystals. Copyright © 2000 John Wiley & Sons, Ltd.

INTRODUCTION

The CsScF₄ crystal presents a typical example of a layered perovskite structure. It is formed by square layers of ScF_6 octahedra connected via common F atoms (here called 'planar' fluorines), and separated with Cs⁺ ions in interlayer holes (the fluorines that belong to a single octahedron are called 'axial'). According to x-ray data and macroscopic measurements,1 the space group of its high-temperature phase is D_{4h}^{-1} , the highest symmetry for such an arrangement. Cooling below 475 K results in a new phase with D_{4h}^{5} symmetry, in which the elementary cell volume is doubled. A second phase transition appears at 317 K leading to a phase with D_{2h}^{13} space group and a further doubling of the cell volume (the main characteristics of these lattices are given in Table 1).

Sc-containing layered perovskites have not been widely studied; such a phase sequence is also unusual for Cscontaining perovskites-like systems as well,² and is similar to that observed in RbAlF4.3 Such transitions in the latter crystal clearly show a displacive character since soft-mode condensations were evidenced by Raman spectroscopy^{4,5} and inelastic neutron scattering.⁶ However, inelastic neutron scattering results and lattice dynamics simulations⁶ also showed that the upper $(D_{4h}^{1} - D_{4h}^{5})$ transition is not just associated with the softening of a single phonon, but of a flat phonon branch. That gave a reason to propose for this transition a mechanism⁷ where the displacive lattice distortion of the upper phase would induce a disordered state at a temperature $T_{\rm L}$ well above the temperature of the phase transition; hence the mechanism of the transition as macroscopically observed would be mainly order-disorder. This T_L temperature may be estimated from the behavior of the soft mode as measured

* Correspondence to: A. Bulou, Laboratoire Physique de l'Etat Condensé, UPRES A CNRS No. 6087, Université du Maine, 72085 Le Mans Cédex g, France; e-mail: alain.bulou@univ-lemans.fr Contract/grant sponsor: INTAS; Contract/grant number: 97-10177.

Contract/grant sponsor: Université du Maine.

Contract/grant sponsor: Krasnoyarsk Regional Science Foundation; Contract/grant number: 8F0039.

by Raman scattering below the actual phase transition. In RbAlF₄ such an estimation gave a T_L value not far from the melting point of the crystal, which made it difficult to put in evidence clearly the various effects expected for a change from an ordered to a disordered state (without any change in the crystal symmetry). The present study was intended to find whether CsScF4 would be a more convenient system where these effects could be more clearly evidenced.

EXPERIMENTAL

Samples for experiments, taken from the same crystallization as in Ref. 1, were selected under a polarizing microscope to minimize possible effects of crystal inhomogeneity due to ferroelastic domain structure, and cut $(1 \times 3 \times 6 \text{ mm}^3)$ along the crystallographic axes of the D_{4h}^{5} phase to obtain polarized Raman spectra. The crystals were transparent and colorless. The temperature during the experiment was fixed within 0.1 K. Spectra were excited by 514.5 nm, 0.5 W argon ion polarized laser radiation. They were obtained partly at 90° geometry with a U-1000 double-grating Raman spectrometer (spectral width 2 cm⁻¹, scan step 1 cm⁻¹), and partly under a microscope in backscattering geometry with a Dilor Z-24 triple monochromator (spectral width 3 cm^{-1} , scan step 1 cm^{-1}).

SYMMETRY ANALYSIS AND EXPERIMENTAL RESULTS

The vibrational representation for the D_{4h}^{-1} phase is

$$\Gamma = A_{1g} + E_g + 4A_{2u} + B_{2u} + 5E_u \tag{1}$$

where only the A_{1g} and E_g modes are Raman active. They correspond to vibrations of 'axial' fluorine atoms normally and in the octahedra sheets, respectively. For the D_{4h} phase one obtains

$$\Gamma = 2A_{1g} + 2A_{2g} + B_{1g} + B_{2g} + 3E_g + 2A_{1u} + 4A_{2u} + 2B_{1u} + 8E_u$$
(2)

	Phase I	Phase II	Phase III
Space group Z	${D_{4h}}^{1}$ 1	${D_{4h}}^5$ 2	${D_{2h}}^{13}_{4}$
Cell para- meters	$egin{aligned} {m{a}_1} & {m{b}_1}(b_1=a_1) & {m{c}_1} & {m{$	$m{a}_2 = m{a}_1 - m{b}_1$ $m{b}_2 = m{a}_1 + m{b}_1(m{b}_2 = m{a}_2)$ $m{c}_2 = m{c}_1$	$a_3 = a_2 + b_2 = 2a_1$ $b_3 = -a_2 + b_2 = 2b_1$ $c_3 = c_2 = c_1$

 Table 1. Symmetry and cell parameters for CsScF₄ crystal

Hence seven Raman-active modes are predicted $(A_{1g}, B_{1g}, B_{2g} \text{ and } E_g \text{ symmetries})$ and so the phase transition under investigation should result in the disappearance of some lines on heating the crystal above the transition point, mainly due to the Brillouin zone reconstruction so that some of them transform to the zone boundary^{4,6} (M point). These modes involve vibrations of 'planar' and 'axial' fluorine atoms.⁶

An overview of the experimental spectra at 348 K is shown in Figs 1–3. This temperature was chosen for initial analysis since it is fairly far from the upper phase transition (well 'inside' the D_{4h} ⁵ phase). The Raman shifts of the lines observed and their attributions are summarized in Table 2.

It should be noted that the present results bring new features with respect to the recently published analysis of the Raman spectra of the CsScF₄ second tetragonal phase.⁸ Mainly it is due to the microRaman technique used in

Table 2. Wavenumbers $(\tilde{\nu})$ and characteristics of Ramanactive modes of CsScF₄ and their attribution in the D_{4h}^{5} phase (T = 348 K)

$\tilde{\nu}/cm^{-1}$	Intensity	Raman component	Irreducible representation
107	Medium	xx, yy, zz	A_{1g}
494	Strong		0
266	Medium	xx, yy	B_{1q}
446	Medium	xy	B_{2a}
32	Medium	yz, xz	Ĕa
158	Very strong		5
248	Medium		

this study, which allows one to choose the best defectless parts of the sample, improves the signal-to-noise ratio and helps to avoid elastic light scattering from defects and intercomponent leaks of spectral lines that were mentioned earlier.⁸ The only leak we failed to avoid completely is from the strongest E_g line at 158 cm⁻¹, which appears slightly in the *xx* component also. Still this minor leak is about an order of magnitude less than the intensity of this line in the *xz* component and may be attributed easily to the scattering on the sample domain structure.

Sample heating results in a continuous decrease of the lines marked in Table 2 as medium, with only slight changes in their wavenumbers. The only exception is the line at 107 cm⁻¹, which dramatically softens on heating (Fig. 4; the E_g line at 158 cm⁻¹ is shown there as a



Figure 1. Overview of CsScF₄ Raman spectra. T = 348 K, y(xz)y and y(xx)y Raman components.



Figure 2. Overview of $CsScF_4$ Raman spectra. T = 348 K, z(xx)z and z(xy)z Raman components. Plasma discharge line is marked with an asterisk.



Figure 3. Overview of CsScF₄ Raman spectra. T = 348 K, y(zx)y and y(zz)y Raman components.

Figure 4. Temperature dependence of Raman-active soft mode in the lower tetragonal phase of CsScF₄.

reference). Its intensity drops continuously on heating, whereas the width remains constant within experimental error (about 1 cm⁻¹). Heating above the phase transition point results in the disappearance of all lines except those at 494 cm⁻¹ (A_{1g}) and 158 cm⁻¹ (E_g), hence they are unambiguously attributed to the vibrations of the 'axial' fluorines alone.

DISCUSSION

The most drastic result observed is the condensation of the full symmetry mode, shown in Fig. 4. The temperature dependence of the square of its wavenumber is shown in Fig. 5, and is almost linear. The wider spread of the experimental points at high temperature is due to the lower intensity of the line and higher noise of the experimental spectra (see Fig. 4). The experimental points have been approximated (by the least-squares method) to a linear temperature dependence and fit it fairly well over all the D_{4h}^{5} phase without saturation at lower temperatures down to the second phase transition at $T_2 = 317$ K, where this wavenumber reaches 113 cm⁻¹. At the same time, extrapolation of this dependence to zero wavenumber gives $T_{\rm L} \approx 770$ K, which is much higher than the transition point $T_1 = 475$ K where macroscopic breaking occurs;1 the latter agrees well with the disappearance of lines that we observed. Hence in spite of the continuous reconstruction of the crystal dynamics and hence the structure over all the D_{4h}^{5} phase, and the rather small (within a few kelvin) hysteresis effects,¹ an important discontinuity of the softmode wavenumber occurs at the transition, which together with the considerable $T_{\rm L} - T_{\rm I}$ difference gives a marked first-order character to it (although the crystal symmetry allows second order for this transition). As was shown by symmetry analysis,^{4,6,8} there exists only one mode of M_3 symmetry that could induce such a change of crystal symmetry. Its eigenvector corresponds to rotations of

0 500 550 600 650 700 750 800 300 350 400 450 T/K Figure 5. Temperature dependence of the square of the wavenumber of the soft mode.

rigid ScF_6 groups around the z-axis, in-phase along this axis and out-of-phase within perovskite-like layers. Such a temperature dependence of this mode resembles very much that obtained for the $D_{4h}^{1} - D_{4h}^{5}$ phase transition in RbAlF₄.⁴

CONCLUSION

These Raman experiments proved that the tetragonal-tetragonal phase transition in CsScF₄ is of first and close to second order, with a mode softening below the transition temperature. Distortion, which drives this transition, is due to in-phase rotations of rigid ScF₆ groups around the z-axis.

The combination of all typical features of this transition (same eigenvector of the soft mode, absence of its wavenumber saturation down the next transition, important discontinuity of this wavenumber at the transition point, which results in a considerable $T_{\rm L} - T_{\rm 1}$ difference, and absence of distinct hysteresis effects) resembles closely those obtained for the $D_{4h}^{1}-D_{4h}^{5}$ phase transition in RbAlF4,4 and suggests a similar mechanism for it, with a disordered state between the two temperatures.⁷ The considerable difference between the estimated value $T_{\rm L} \approx 770$ K and the melting point (well above 1100 K) of CsScF₄ makes this crystal a promising object for experimental investigations of this state.

Acknowledgments

The authors are grateful to Professor I. N. Flerov for valuable discussions. This work was supported by the INTAS, project No. 97-10177, the Université du Maine (France) and the Krasnoyarsk Regional Science Foundation, project No. 8F0039.





- Aleksandrov KS, Voronov VN, Kruglik AI, Melnikova SV, Flerov IN. *Fis. Tverd. Tela.* 1988; **30**: 3325.
 Aleksandrov KS, Anistratov AT, Beznosikov BV, Fedoseeva NV. *Phase Transitions in ABX*₃ *Haloid Crystals*. Nauka: Neurithiank 4021 (in Puerity). Aleksandrev KS, Parameterity Novosibirsk, 1981 (in Russian); Aleksandrov KS, Beznosikov BV. Perovskite-like Crystals. Nauka: Novosibirsk, 1997 (in Russian).
- 3. Bulou A, Nouet J. J. Phys. C: Solid State Phys. 1982; 15: 183.
- 4. Bulou A, Rousseau M, Nouet J, Loyzance PL, Mokhlisse R, Couzi M. J. Phys. C: Solid State Phys. 1983; 16: 4527.
 5. Aleksandrov KS. Kristallografiya 1987; 32: 661.
- 6. Bulou A, Rousseau M, Nouet J, Hennion B. J. Phys. Condens. Matter 1989; 1: 4553.
- 7. Bulou A, Rousseau M, Nouet J. Ferroelectrics 1990; 104: 373.
- 8. Krylov AS, Shmygol IV, Shebanin AP, Vtyurin AN, Ageev AG, Fleisher Ol. Izv. Ross. Akad. Nauk Ser. Fiz. 1998; 62: 1550.